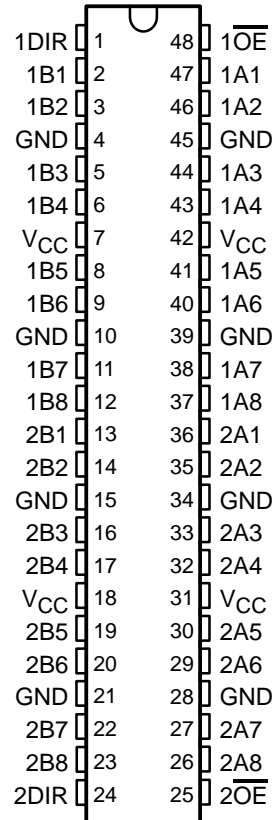


SN54ABT162245, SN74ABT162245 16-BIT BUS TRANSCEIVERS WITH 3-STATE OUTPUTS

SCBS239D – MARCH 1993 – REVISED JANUARY 1997

- **Members of the Texas Instruments Widebus™ Family**
- **A-Port Outputs Have Equivalent 25-Ω Series Resistors, So No External Resistors Are Required**
- **State-of-the-Art EPIC-II B™ BiCMOS Design Significantly Reduces Power Dissipation**
- **Latch-Up Performance Exceeds 500 mA Per JEDEC Standard JESD-17**
- **Typical V_{OLP} (Output Ground Bounce) < 1 V at V_{CC} = 5 V, T_A = 25°C**
- **Distributed V_{CC} and GND Pin Configuration Minimizes High-Speed Switching Noise**
- **Flow-Through Architecture Optimizes PCB Layout**
- **Package Options Include Plastic 300-mil Shrink Small-Outline (DL) and Thin Shrink Small-Outline (DGG) Packages and 380-mil Fine-Pitch Ceramic Flat (WD) Package Using 25-mil Center-to-Center Spacings**

SN54ABT162245 . . . WD PACKAGE
SN74ABT162245 . . . DGG OR DL PACKAGE
(TOP VIEW)



description

The 'ABT162245 are 16-bit noninverting 3-state transceivers designed for synchronous two-way communication between data buses. The control-function implementation minimizes external timing requirements.

These devices can be used as two 8-bit transceivers or one 16-bit transceiver. They allow data transmission from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (\overline{OE}) input can be used to disable the device so that the buses are effectively isolated.

The A-port outputs, which are designed to source or sink up to 12 mA, include equivalent 25-Ω series resistors to reduce overshoot and undershoot.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54ABT162245 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74ABT162245 is characterized for operation from –40°C to 85°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

**TEXAS
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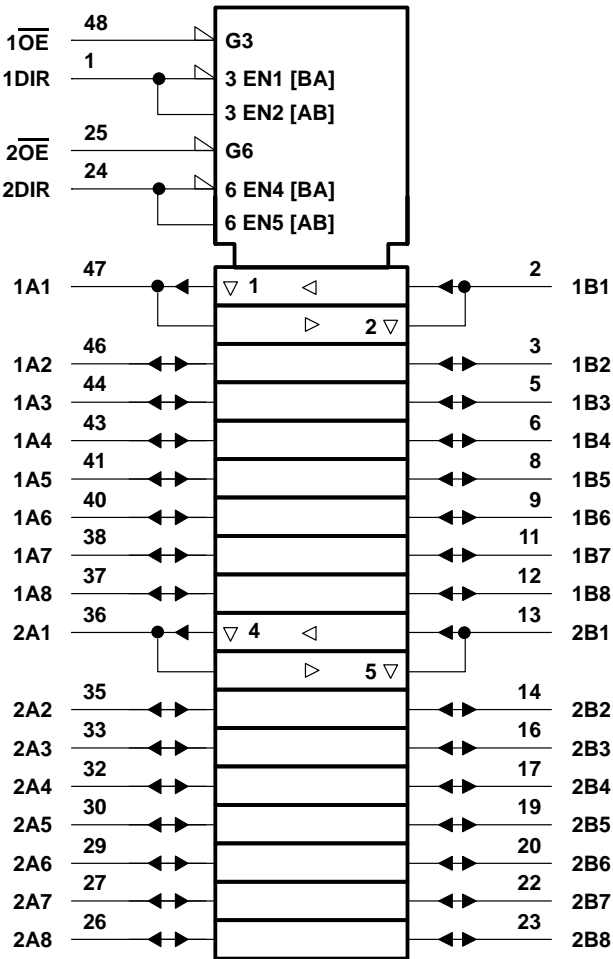
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FUNCTION TABLE
(each 8-bit section)

INPUTS		OPERATION
OE	DIR	
L	L	B data to A bus
L	H	A data to B bus
H	X	Isolation

logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

The diagram shows a 2-to-4 decoder implemented using two 74148 3-to-8 decoders. The first decoder (left) has inputs 1DIR, 1A1, and 1B1. The second decoder (right) has inputs 48, 47, and 2. The outputs of the first decoder are connected to the inputs of the second decoder. The final outputs are labeled 1, 2, 3, 4, 5, 6, 7, and 8.

Logic diagram of the 2421 BCD-to-Excess-3 code converter. The circuit uses two 3-input AND gates and two 2-input inverters. The inputs are 2DIR (pin 24), 2OE (pin 25), 2A1 (pin 36), and 2B1 (pin 13). The outputs are grouped by a bracket at the bottom.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T _A = 25°C			SN54ABT162245		SN74ABT162245		UNIT
				MIN	TYP†	MAX	MIN	MAX	MIN	MAX	
V _{IK}		V _{CC} = 4.5 V, I _I = -18 mA		-1.2			-1.2		-1.2		V
V _{OH}	A port	V _{CC} = 5 V, I _{OH} = -1 mA		3.8			2.5		2.5		V
		V _{CC} = 4.5 V	I _{OH} = -1 mA	3.3			3		3		
			I _{OH} = -3 mA	3.1			3		3.1		
			I _{OH} = -12 mA	2.6*					2.6		
	B port	V _{CC} = 5 V, I _{OH} = -3 mA		3			3		3		
		V _{CC} = 4.5 V	I _{OH} = -3 mA	2.5			2.5		2.5		
			I _{OH} = -24 mA				2				
			I _{OH} = -32 mA	2*					2		
V _{OL}	A port	V _{CC} = 4.5 V	I _{OL} = 12 mA	0.8			0.8		0.8		V
	B port		I _{OL} = 48 mA	0.45			0.45		0.45		
				I _{OL} = 64 mA	0.55*					0.55	
V _{hys}					100						
I _I	Control inputs	V _{CC} = 5.5 V, V _I = V _{CC} or GND		±1			±1		±1		μA
	A or B ports			±20			±20		±20		
I _{OZH} §		V _{CC} = 5.5 V, V _O = 2.7 V		10			10		10		μA
I _{OZL} §		V _{CC} = 5.5 V, V _O = 0.5 V		-10			-10		-10		μA
I _{off}		V _{CC} = 0, V _I or V _O ≤ 4.5 V		±100					±100		μA
I _{CEX}		V _{CC} = 5.5 V, V _O = 5.5 V	Outputs high	50			50		50		μA
I _O ¶	A port	V _{CC} = 5.5 V, V _O = 2.5 V		-25	-50	-100‡	-25	-90	-25	-100	mA
	B port			-50	-100	-180	-50	-180	-50	-180	
I _{CC}	A or B ports	V _{CC} = 5.5 V, I _O = 0, V _I = V _{CC} or GND	Outputs high	2			2		2		mA
			Outputs low	32			32		32		
			Outputs disabled	2			2		2		
ΔI _{CC} #	Data inputs	V _{CC} = 5.5 V, One input at 3.4 V, Other inputs at V _{CC} or GND	Outputs enabled	1			2		2		mA
			Outputs disabled	0.05			1		0.05		
	Control inputs	V _{CC} = 5.5 V, One input at 3.4 V, Other inputs at V _{CC} or GND	1.5			1.5		1.5			
C _i		V _I = 2.5 V or 0.5 V		3							pF
C _{io}		V _O = 2.5 V or 0.5 V		6							pF

* On products compliant to MIL-PRF-38535, this parameter does not apply.

† All typical values are at V_{CC} = 5 V.

‡ This limit applies only to the SN74ABT162245.

§ The parameters I_{OZH} and I_{OZL} include the input leakage current.

¶ Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.



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switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $C_L = 50$ pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = 5$ V, $T_A = 25^\circ$ C			SN54ABT162245		SN74ABT162245		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t_{PLH}	A	B	1	2.2	3.4	1	4.1	1	3.9	ns
t_{PHL}			1	2.3	3.7	1	4.4	1	4.2	
t_{PLH}	B	A	1	2.7	4.1	1	4.9	1	4.6	ns
t_{PHL}			1.5	3.1	4.6	1.5	5.2	1.5	5.1	
t_{PZH}	\overline{OE}	B	1	3.6	5.2	1	6.4	1	6.3	ns
t_{PZL}			1	3.7	5.4	1	6.5	1	6.4	
t_{PHZ}	\overline{OE}	B	2	4.4	5.8	2	6.4	2	6.3	ns
t_{PLZ}			1.5	3.3	4.7	1.5	5.6	1.5	5.2	
t_{PZH}	\overline{OE}	A	1.5	4.1	6	1.5	7.2	1.5	7.1	ns
t_{PZL}			1.5	4.3	6.1	1.5	7.3	1.5	7	
t_{PHZ}	\overline{OE}	A	2	4.5	6.1	2	6.8	2	6.6	ns
t_{PLZ}			1.5	3.7	5.1	1.5	6.1	1.5	5.7	



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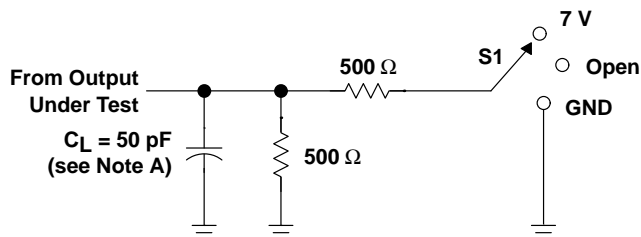
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16-BIT BUS TRANSCEIVERS

WITH 3-STATE OUTPUTS

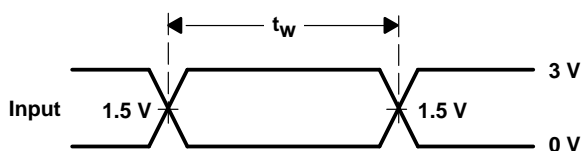
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PARAMETER MEASUREMENT INFORMATION

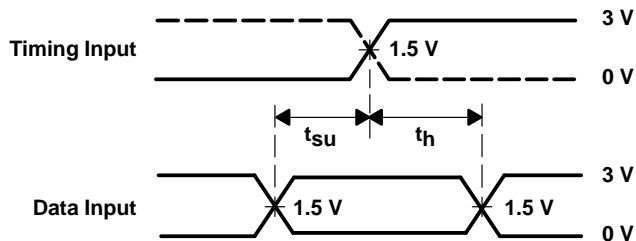


LOAD CIRCUIT

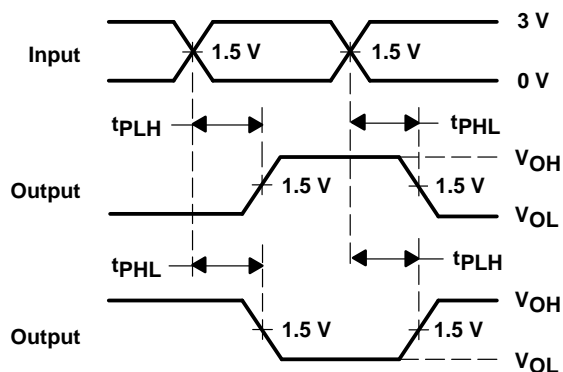
TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	7 V
t_{PHZ}/t_{PZH}	Open



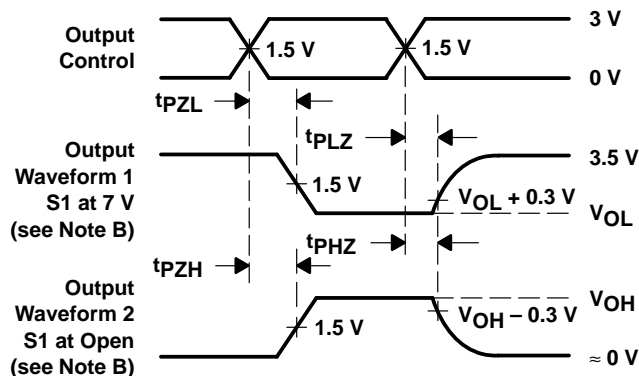
VOLTAGE WAVEFORMS
PULSE DURATION



VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
INVERTING AND NONINVERTING OUTPUTS



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES
LOW- AND HIGH-LEVEL ENABLING

- NOTES:
- C_L includes probe and jig capacitance.
 - Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - All input pulses are supplied by generators having the following characteristics: $PRR \leq 10 \text{ MHz}$, $Z_O = 50 \Omega$, $t_r \leq 2.5 \text{ ns}$, $t_f \leq 2.5 \text{ ns}$.
 - The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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